1.5 – 2.5 GHz LNA Switch PA

Technical Data

Features

- GaAs MMIC LNA-Switch-Power Amp for 1.5 – 2.5 GHz **Transceiver Use**
- LNA: 2.2 dB NF, 13 dB G_a @ **1.9 GHz**
- Switch: 55 dBm OIP @ **1.9 GHz**
- Power Amp: +4 dBm in, +27.5 dBm out, 23.5 dB Gain, 35% n_{add} @ 1.9 GHz
- 3 or 5 V Operation
- **JEDEC Standard SSOP-28** Surface Mount Package

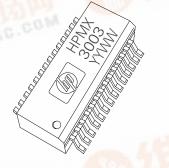
Applications

- Personal Communications Systems (PCS)
- Cordless Telephone Systems
- 2400 MHz Wireless LANs and ISM Band Spread **Spectrum Applications**

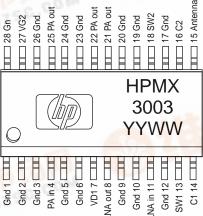
Functional Block Diagram LNA in LNA out SW1 C1 (Antenna SW2 • PA out VGIOM VD2

Vģ2

Plastic SSOP-28



Package Pin Configuration



HPMX-3003

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Description

Hewlett-Packard's HPMX-3003 combines a Low Noise Amplifier, GaAs MMIC switch, and 27.5 dBm power amp in a single miniature 28 lead surface mount plastic package. This RFIC would typically serve as the "front end" and power stage of a battery operated wireless transceiver for PCS or ISM band use. Each section of the RFIC can also be used independently.

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The single-supply LNA makes use of the low noise characteristics of GaAs to create a matched, broadband amplifier with target performance of 13 dB gain and 2.2 dB noise figure. The switch provides +55 dBm IP3 for linear operation. The power amplifier produces up to 820 mW with 35% power added efficiency.

The HPMX-3003 is fabricated with Hewlett-Packard's GaAs MMIC process, and features a nominal 0.5 micron recessed Schottkybarrier-gate, gold metallization, and silicon nitride passivation to produce MMICs with superior performance, uniformity and reliability.

Symbol	Parameter	Units	Absolute Maximum ^[1] LNA	Absolute Maximum ^[1] Switch	Absolute Maximum ^[1] Power Amp
P _{diss}	Power Dissipation ^[2,3]	mW	250 ^[2,3]		1500 ^[2,3]
P _{in}	CW RF Input Power	dBm	+20	+33	+20
Vd	Device Voltage	V	8	—	8
V _{cont}	Control Voltage	V		-6	
T _{ch}	Channel Temperature	°C	175	175	175
T _{STG}	Storage Temperature	°C	-65 to 150	-65 to 150	-65 to 150

HPMX-3003 Absolute Maximum Ratings^[1]

Notes:

1. Operation of this device above any of these limits may cause permanent damage.

2.
$$T_{case} = 25^{\circ}C$$

3. Derate at 18.2 mW/°C for $T_C > 78$ °C

Recommended operating range of V_{cc} = 2.7 to 5.5 V, T_a = -40 to + 85 °C

HPMX-3003 Standard Test Conditions

Unless otherwise stated, all test data was taken on packaged parts under the following conditions:

$$\begin{split} T_a &= 25 \,^{\circ}\text{C}, Z_o = 50 \,\Omega \\ V_{cc} &= +3.0 \,\text{VDC}, V_{control} = -3.0 \,\text{VDC}, V_{D1} = +3.6 \,\text{VDC} \\ \text{LNAP}_{in} &= -20 \,\text{dBm}, \text{PAP}_{in} = +4 \,\text{dBm}, \text{frequency} = 1.9 \,\text{GHz} \\ \text{Perfomance cited is performance in test circuit shown in Figure 17.} \end{split}$$

HPMX-3003 Guaranteed Electrical Specifications

Standard test conditions apply unless otherwise noted.

Symbol	Parameters and Test Conditions	Units	Min.	Тур.	Max.
G _{test}	LNA gain through switch	dB	9.0	11	
Pout	Output power through switch	dBm	24.0	25.5	
I _d LNA	LNA bias current	mA		6.5	9.5

Thermal Resistance^[2]: $\theta_{jc} = 55^{\circ}C/W$

HPMX-3003 Summary Characterization Information

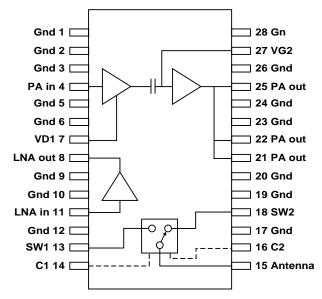
Standard test conditions apply unless otherwise noted. All information tested in 1900 MHz Test Circuit, and reflects performance of test circuit at 1900 MHz.

Symbol	Parameters and Test Conditions	Units	Тур			
LNA						
NF	Noise Figure		dB	2.2		
$ S_{21} ^2$	$50\Omega\mathrm{Gain}$		dB	13		
IRL	Input Return Loss		dB	15		
ORL	Output Return Loss			12		
IIP ₃	Input Third Order Intercept		dBm	-1		
Switch						
P _{1dB}	Output Power where insertion loss is increased by 1 dB	$\Delta C1$ to $C2 = 3$ V	dBm	+23		
P _{1dB}	Output Power where insertion loss is increased by $1 \text{ dB}^{[1]}$	$\Delta C1 \text{ to } C2 = 5 \text{ V}$	dBm	+29		
IP_3	Third Order Intercept		dBm	+55		
S_{21} on	Insertion Loss, on channel		dB	0.8		
S_{21} off	Isolation, off channel		dB	15		
IRLon	Return Loss, on channel		dB	26		
IRLoff	Return Loss, off channel		dB	0.5		
Power amp (Vg =8 V required)						
GP	Gain $V_{D1} = 3$	$.6 \text{ V}, \text{P}_{\text{in}} = +4 \text{ dBm}$	dB	23.5		
$\eta_{PA_{add}}$	Power Added Efficiency	$V_{D1} = 3.6 V$	%	35		
Pout	Output Power $V_{D1} = 3$	$.6 \text{ V}, \text{P}_{\text{in}} = +4 \text{ dBm}$	dBm	+27.5		
I _d PA	Transmit Current $V_{D1} = 3$	$.6 \text{ V}, \text{P}_{\text{in}} = +4 \text{ dBm}$	mA	450		

Note:

1. The P_{1dB} of the switch can be improved by increasing the difference between the values of C1 and C2 from the normal $3\,V\,(+23\,dB\,P_{1dB})$ to $5\,V\,(+29\,dB\,P_{1dB})$.

HPMX-3003 Pin Description

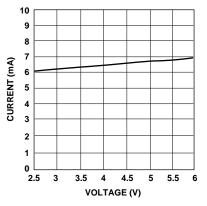


No.	Mnemonic	Description	Typical Signal	Description	
1 2	Gnd Gnd	ground ground	0 V 0 V	Short path with minimal parasitics. Ground pins are also the primary thermal path for heatsinking the device.	
3	Gnd	ground	0 V		
4	PAin	input to Power Amplifier	DC: -0.75 V RF: +4 dBm	Bias through 500Ω resistor and 100 pF capacitor. 50Ω transmission line with DC blocking capacitor (>24 pF) to input. Shunt 2.7 pF used on test board to match input at 1.9 GHz.	
$5 \\ 6$	Gnd Gnd	ground ground	0 V 0 V	Short path with minimal parasitics. Ground pins are also the primary thermal path for heatsinking the device.	
7	VD1	Drain bias of PA stage 1	+3V,100mA	Set drain bias to 3 V (can be tied to same rail as PA out). Bypass with 100 pF capacitor at pin.	
8	LNA out	output of LNA	DC: +3V, 5 mA RF: -7 dBm	Bias through 5 nH choke (printed on PC board) and 100 pF bypass capacitor to 10Ω resistor and 1000 pF bypass capacitor. Can be operated from 3 to 5 V supply line. 50 Ω transmission line with DC block (>24 pF) to receiver.	
9 10	Gnd Gnd	ground ground	0 V 0 V	Short path with minimal parasitics. Ground pins are also the primary thermal path for heatsinking the device.	
11	LNA in	input of LNA	DC: 0 V RF: -20 dBm	50Ω transmission line from switch. Input blocking capacitor (24 pF) and shunt 5 nH inductor to ground (noise match at 1.9 GHz) required. Typically a filter is employed between the LNA input and the switch.	
12	Gnd	ground	0 V	Short path with minimal parasitics. Ground pins are also the primary thermal path for heatsinking the device.	
13	SW1	switch terminal 1	DC: 0 V RF: -20 dBm	Switch input or output. Symmetrical with SW2. 50 Ω transmission line to LNA (or PA). Line should not carry DC voltage.	
14	C1	switch control 1	closed: 0 V open: -3 to -5 V	High impedance line to control switch, used in conjunction with C2. C2 should be open when C1 is closed.	
15	Antenna	switch center pole	DC: 0 V RF: +26 dBm	$50~\Omega$ transmisson line to/from antenna. Line should not carry DC voltage.	
16	C2	switch control 2	closed: 0 V open: -3 to -5 V	High impedance line to control switch, used in conjunction with C1. C1 should be open when C2 is closed.	
17	Gnd	ground	0 V	Short path with minimal parasitics. Ground pins are also the primary thermal path for heatsinking the device.	
18	SW2	switch terminal 2	DC: 0 V RF: +4 dBm	Switch input or output. Symmetrical with SW1. 50 Ω transmission line to PA (or LNA). Line should not carry DC voltage.	
19 20	Gnd Gnd	ground ground	0 V 0 V	Short path with minimal parasitics. Ground pins are also the primary thermal path for heatsinking the device.	
21 22	PA out PA out	output of PA output of PA	DC: 3 V, 350 mA RF: +27 dBm		
23 24	Gnd Gnd	ground ground	0 V 0 V	Short path with minimal parasitics. Ground pins are also the primary thermal path for heatsinking the device.	
25	PA out	output of PA	DC: 3 V, 350 mA RF: +27 dBm	Leave unconnected; use pins 21 & 22 for PA out.	
26	Gnd	ground	0 V	Short path with minimal parasitics. Ground pins are also the primary thermal path for heatsinking the device.	
27	VG2	Gate bias on PA stage 2	-0.75V	Provide bias through 10Ω resistor. Bypass to ground at pin with 10 pF capacitor, and on power supply side of resistor with 1000 pF capacitor.	
28	Gnd	ground	OV	Short path with minimal parasitics. Ground pins are also the primary thermal path for heatsinking the device.	

HPMX-3003 Pin Description Table

HPMX-3003 Typical Performance

Standard test conditions apply unless otherwise noted. 2.4 GHz performance is performance in test circuit shown in Figure 18. Some aspects of performance are determined by the test circuit impedances.



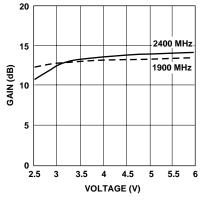


Figure 2. LNA Current vs. Device Voltage at 1900 MHz.

Figure 3. LNA Gain vs. Device Voltage and Frequency.

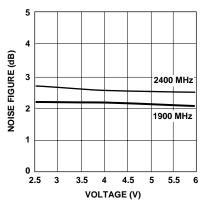


Figure 4. LNA Noise Figure vs. Device Voltage and Frequency.

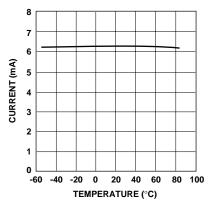


Figure 5. LNA Current vs. Temperature at 1900 MHz.

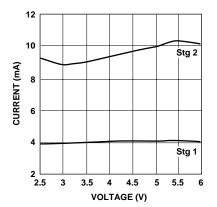


Figure 8. PA Current vs. Device Voltage at 1900 MHz.

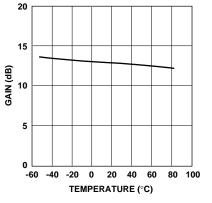


Figure 6. LNA Gain vs. Temperature at 1900 MHz.

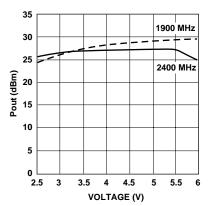


Figure 9. PA Output Power vs. Supply Voltage and Frequency.

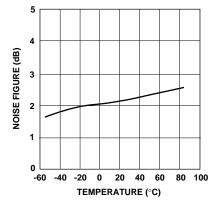


Figure 7. LNA Noise Figure vs. Temperature at 1900 MHz.

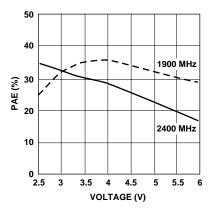
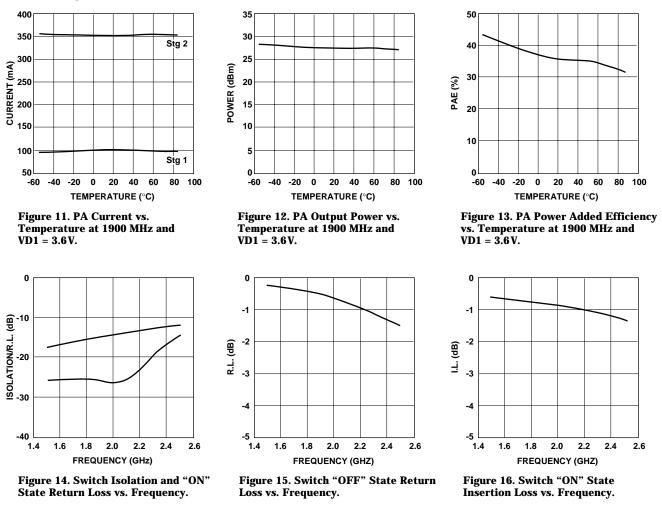


Figure 10. PA Power Added Efficiency vs. Supply Voltage and Frequency.

HPMX-3003 Typical Performance, continued

Standard test conditions apply unless otherwise noted. 2.4 GHz performance is performance in test circuit shown in Figure 18. Some aspects of performance are determined by the test circuit impedances.



HPMX-3003 Typical Scattering Parameters for the LNA, Common Source $Z_{-} = 50 \text{ O} \text{ V}_{-} = 3 \text{ V} \text{ L}_{-} = 5 \text{ mA}$

Frequency	uency S ₁₁		\mathbf{S}_{21}		\mathbf{S}_{12}		\mathbf{S}_{22}	
GHz	Mag	Ang	Mag	Ang	Mag	Ang	Mag	Ang
1.0	0.97	-27	2.00	158	0.035	-12	0.91	-22
1.2	0.96	-33	2.06	150	0.036	-17	0.91	-27
1.4	0.95	-40	2.13	142	0.037	-23	0.90	-31
1.6	0.94	-47	2.20	134	0.038	-30	0.88	-36
1.8	0.92	-54	2.28	125	0.038	-39	0.87	-41
2.0	0.90	-62	2.36	117	0.039	-49	0.86	-46
2.2	0.88	-70	2.45	109	0.039	-62	0.84	-50
2.4	0.85	-79	2.54	100	0.040	-77	0.83	-55
2.6	0.82	-89	2.63	90	0.042	-95	0.81	-60
2.8	0.78	-99	2.71	81	0.045	-115	0.79	-65
3.0	0.75	-110	2.79	71	0.050	-135	0.78	-71

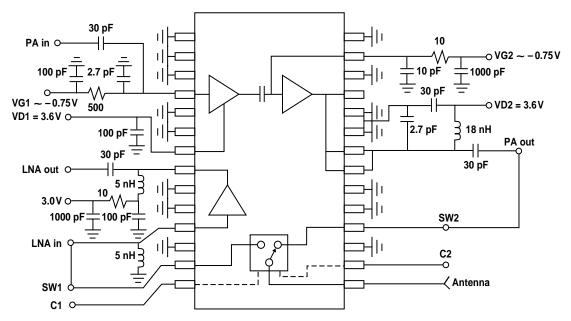


Figure 17. HPMX-3003 Test Circuit (1900 MHz).

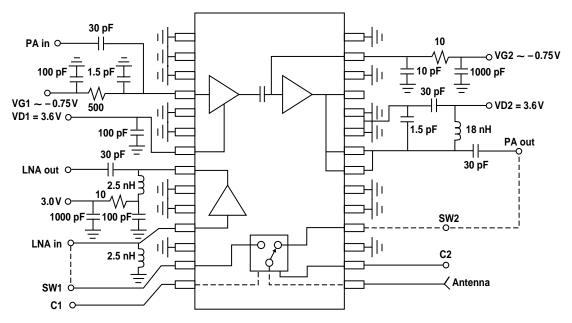
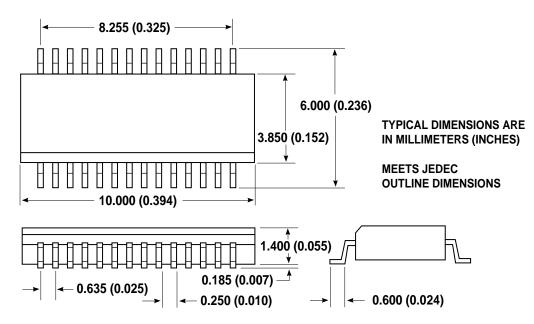


Figure 18. HPMX-3003 Test Circuit (2400 MHz).

JEDEC Standard SSOP-28 Package Outline Drawing



Part Number Ordering Information

Part Number	No. of Devices	Container
HPMX-3003-TR1	1000	Tape and Reel
HPMX-3003-BLK	25	Таре